

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All recreations are done with the approval of the OCM.

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

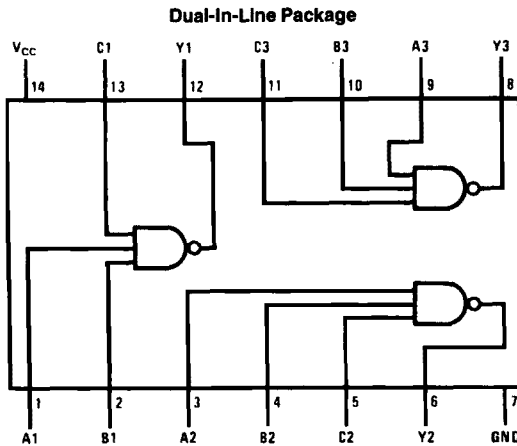
DM54L10

Triple 3-Input NAND Gates

General Description

This device contains three independent gates each of which performs the logic NAND function.

Connection Diagram



TL/F/6619-1

Order Number **DM54L10J** or **DM54L10W**
See NS Package Number **J14A** or **W14B**

Function Table

$$Y = \overline{ABC}$$

Inputs			Output
A	B	C	Y
X	X	L	H
X	L	X	H
L	X	X	H
H	H	H	L

H = High Logic Level

L = Low Logic Level

X = Either Low or High Logic Level

Absolute Maximum Ratings (Note)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage	8V
Input Voltage	5.5V
Operating Free Air Temperature Range	
DM54L	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C

Note: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Recommended Operating Conditions

Symbol	Parameter	DM54L10			Units
		Min	Nom	Max	
V _{CC}	Supply Voltage	4.5	5	5.5	V
V _{IH}	High Level Input Voltage	2			V
V _{IL}	Low Level Input Voltage			0.7	V
I _{OH}	High Level Output Current			-0.2	mA
I _{OL}	Low Level Output Current			2	mA
T _A	Free Air Operating Temperature	-55		125	°C

Electrical Characteristics over recommended operating free air temperature (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 1)	Max	Units
V _{OH}	High Level Output Voltage	V _{CC} = Min, I _{OH} = Max V _{IL} = Max	2.4	3.3		V
V _{OL}	Low Level Output Voltage	V _{CC} = Min, I _{OL} = Max V _{IH} = Min		0.15	0.3	V
I _I	Input Current @ Max Input Voltage	V _{CC} = Max, V _I = 5.5V			0.1	mA
I _{IH}	High Level Input Current	V _{CC} = Max, V _I = 2.4V			10	μA
I _{IL}	Low Level Input Current	V _{CC} = Max, V _I = 0.3V			-0.18	mA
I _{OS}	Short Circuit Output Current	V _{CC} = Max (Note 2)	-3		-15	mA
I _{COH}	Supply Current with Outputs High	V _{CC} = Max		0.33	0.6	mA
I _{CCL}	Supply Current with Outputs Low	V _{CC} = Max		0.87	1.53	mA

Switching Characteristics at V_{CC} = 5V and T_A = 25°C (See Section 1 for Test Waveforms and Output Load)

Symbol	Parameter	Conditions	Min	Max	Units
t _{PLH}	Propagation Delay Time Low to High Level Output	R _L = 4 kΩ, C _L = 50 pF		60	ns
t _{PHL}	Propagation Delay Time High to Low Level Output			60	ns

Note 1: All typicals are at V_{CC} = 5V, T_A = 25°C.

Note 2: Not more than one output should be shorted at a time.